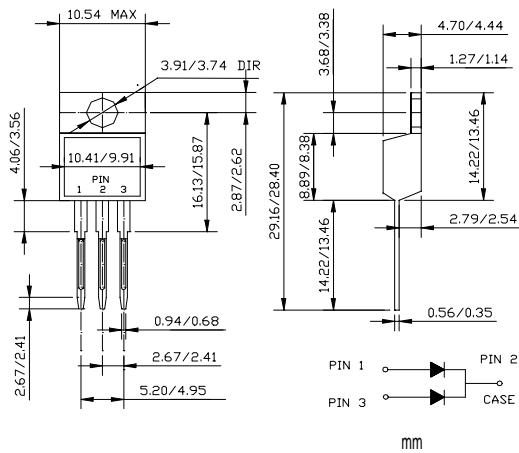


TO-220AB



FEATURES

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

MECHANICAL DATA

- ◇ Case: JEDEC TO-220AB, molded plastic body
- ◇ Terminals: Leads, solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Weight: 0.08 ounce, 2.24 grams
- ◇ Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

PARAMETER	SYMBOL	MBR1040CT	MBR1045CT	MBR1050CT	MBR1060CT	MBR1080CT	MBR1090CT	MBR10100CT	MBR10150CT	MBR10200CT	UNITS						
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	40	45	50	60	80	90	100	150	200	V						
Maximum RMS Voltage	V_{RMS}	28	31.5	35	42	56	63	70	105	140	V						
Maximum DC Blocking Voltage	V_{DC}	40	45	50	60	80	90	100	150	200	V						
Maximum Average Forward Current (See fig.1)	$I_{F(AV)}$	10									A						
Peak Forward Surge Current : 8.3ms single half sine-wave superimposed on rated load(JEDEC method)	I_{FSM}	150									A						
Maximum Forward Voltage at 5A, per leg	V_F	0.7		0.75		0.8		0.9		V							
Maximum DC Reverse Current $T_J=25^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_J=125^{\circ}\text{C}$	I_R	0.05 20									mA						
Typical Thermal Resistance	$R_{\theta JC}$	2									$^{\circ}\text{C} / \text{W}$						
Operating and Storage Junction Temperature Range	T_J, T_{STG}	-55 to +150	-65 to +175														

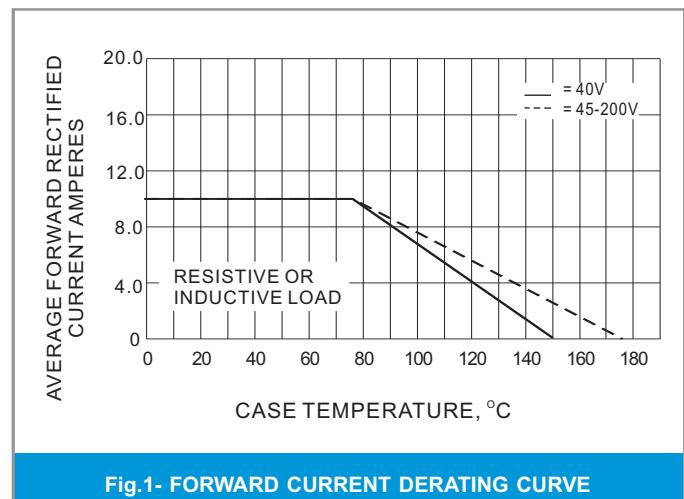


Fig.1- FORWARD CURRENT DERATING CURVE

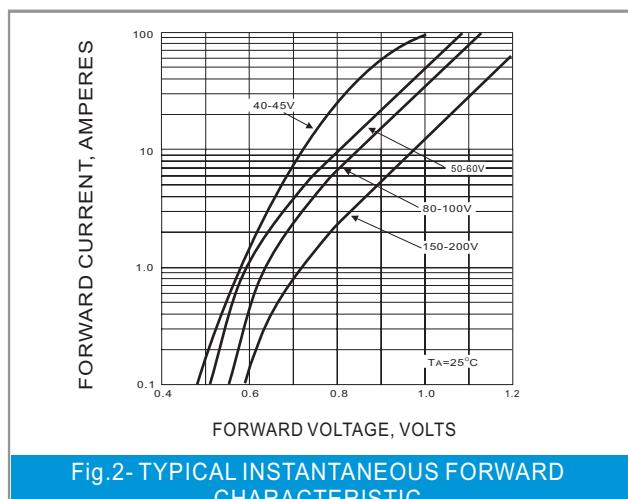


Fig.2- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC

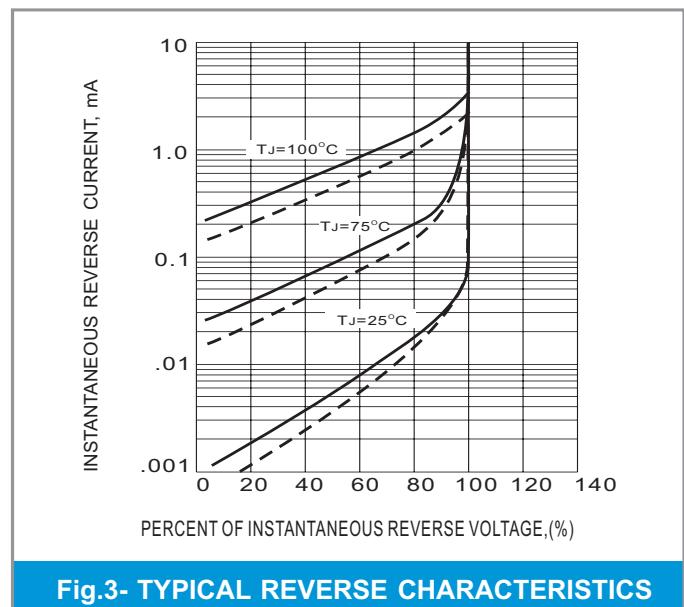


Fig.3- TYPICAL REVERSE CHARACTERISTICS

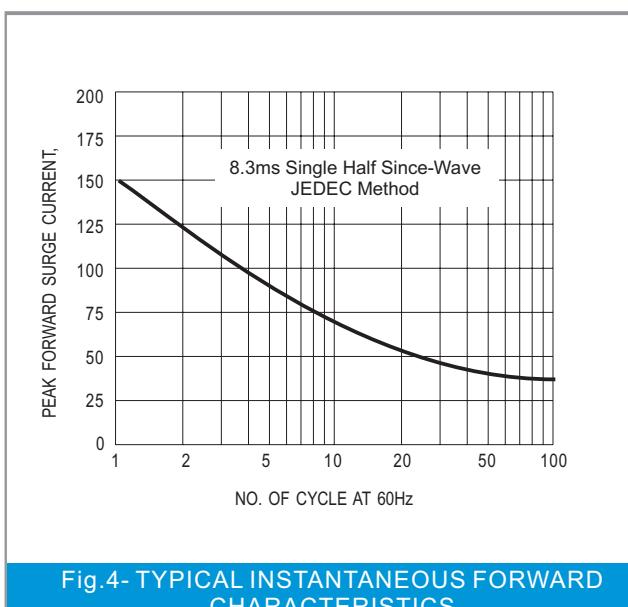


Fig.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS